

NPN D44H SERIES PNP D45H SERIES

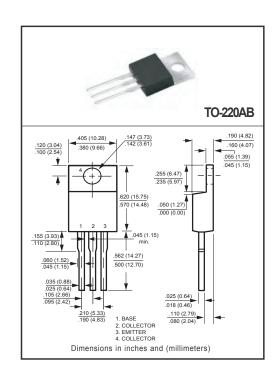
10 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 60,80 VOLTS

FEATURES

- * ...for general purpose power amplification and switching such as output or driver stages in applications such as switching regulators, converter and power ampifiers.
- * Low Collector-Emitter Saturation Voltage VCE_(sat) = 1.0 V (max.) @8.0A
- * Fast Switching Speeds
- * Complementary Pairs Simplifies Designs

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.



MAXIMUM RATINGES (@ TA = 25° C unless otherwise noted)

RATINGS	SYMBOL	D44H	UNITS	
		8	10, 11	UNITS
Collector-Emitter voltage	V _{CEO}	60	80	V
Emitter-Base voltage	V _{EB}		V	
Collector current-Continutious -Peak (Note 1)	Ic	1 2	А	
Collector Power dissipation @T _C =25°C @T _A =25°C	Pd	5 1.	W	
Thermal Resistance	R ₀ JA	75		
	R ₀ JC	2.5		
Lead Temperature for Soldering Purposes: 1/8" from case for 5 sec.	TL	2	°C	
Operating and Storage Junction Temperature Range	T _{J,} Tstg	-55 to	°C	

Notes: 1. Pulse Width \leq 6.0mS, Duty Cycle \leq 50%

2. "Fully RoHS Compliant", "100% Sn Plating (Pb-free)".

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ELECTRICAL CHARACTERISTICS (@ TA = 25°C unless otherwise noted)

CHARACTERISTICS			MIN	TYP	MAX	UNITS
Collector cutoff current (V _{CE} = Rated V _{CEO} ,V _{BE} = 0)			-	-	10	uA
Emitter cutoff current (V _{EB} = 5Vdc)			-	-	100	uA
DC current gain (V _{CE} = 1.0V,I _C = 2.0Adc)	D44H10,D45H10	- h _{FE}	35	-	-	-
	D44H8,11 D45H8,11		60	-	-	-
DC current gain (V _{CE} = 1.0V,I _C = 4.0Adc)	D44H10,D45H10	. h _{FE}	20	-	-	-
	D44H8,11 D45H8,11] "FE	40	-	-	-
Collector-emitter saturation voltage (I _C = 8.0Adc,I _B = 0.4Adc)	D44H/D45H8,11	V _{CE(sat)}	-	-	1.0	V
(I _C = 8.0Adc,I _B = 0.8Adc)	D44H/D45H10		-	-	1.0	V
Base-emitter saturation voltage (I _C = 8.0Adc,I _B = 0.8Adc)			-	-	1.5	V
Collector Capacitance (V _{CB} = 10V, f _{test} = 1.0 MHz)	D44H Series	Ccb	-	130	-	pF
	D45H Series	Ccb	-	230	-	pF
Gain Bandwidth Product (I _C = 0.5Adc, V _{CE} = 10Vdc, f=20 MHz)	D44H Series	f _T	-	50	-	MHz
	D45H Series	''	-	40	-	MHz
Delay and Rise Times (I _C = 5.0Adc, I _{B1} = 0.5Adc)	D44H Series	t _d + t _r	-	300	-	nS
	D45H Series	'd' 'r	-	135	-	nS
Storage Time (I _C = 5.0Adc, I _{B1} =I _{B2} = 0.5Adc)	D44H Series	t _s	-	500	-	nS
	D45H Series	ıs	-	500	1	nS
Fall Time (I _C = 5.0Adc, I _{B1} =I _{B2} = 0.5Adc)	D44H Series	t _f	-	140	-	nS
	D45H Series	4	-	100	-	nS

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RATING AND CHARACTERISTICS CURVES (D44H and D45H Series)

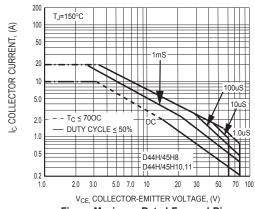


Figure Maximum Rated Forward Bias Safe Operating Area



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